ESD Protection Diodes Silicon Epitaxial Planar

# DF2B6M4BSL

#### 1. General

The DF2B6M4BSL is a TVS diode (ESD protection diode) that protects semiconductor components from static electricity and noise in electronic device antennas and high-speed interface ports.

This product has ultra-low capacitance characteristics, it is possible to suppress the deterioration of signal quality that is a concern in antennas and high-speed signal lines. And the DF2B6M4BSL provides low  $V_{peak}$  voltage when ESD is applied and superior protective performance.

DF2B6M4BSL is housed in an ultra-compact package (0.62 mm  $\times$  0.32 mm) to meet applications that require a small footprint.

#### 2. Applications

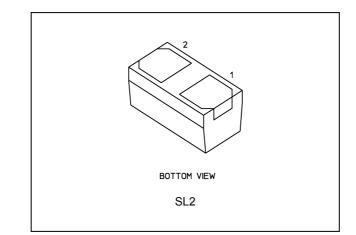
Mobile Equipment IoT Equipment Wearable Equipment

- Wi-Fi
- $\cdot$  Anntena
- $\cdot \ \mbox{DisplayPort Interface}$
- $\cdot\,$  USB/HDMI
- · PCI Express
- Note: This product is designed for protection against electrostatic discharge (ESD) and is not intended for any other purpose, including, but not limited to, voltage regulation.

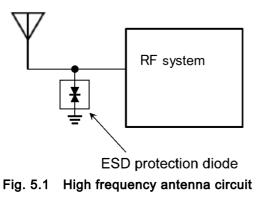
#### 3. Features

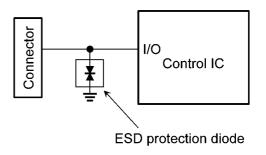
- (1) Suitable for use with a 5.0 V signal line. (V<sub>RWM</sub>  $\leq$  5.5 V)
- (2) Low harmonic distortion
  - f = 2.4 GHz, 20 dBm input
  - 2nd Harmonics: -65.5 dBm (Reference)
  - 3rd Harmonics: -54.4 dBm (Reference)
  - f = 5.0 GHz, 20 dBm input 2nd Harmonics: -64.7 dBm (Reference) 3rd Harmonics: -55.5 dBm (Reference)
- (3) Low  $V_{\text{peak}}$ :  $V_{\text{CL-max-peak}} = 215 \text{ V}$  (Reference) (@IEC61000-4-2(Contact), +8 kV)
- (4) Compact package is suitable for use in high density board layouts such as in mobile devices.
   (0.62 mm × 0.32 mm size (Nickname: SL2))

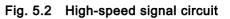
#### 4. Packaging



#### 5. Example of Circuit Diagram







#### 6. Quick Reference Data

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Working peak reverse voltage	V <sub>RWM</sub>	(Note 1)	—	_	—	5.5	V
Total capacitance	Ct		V <sub>R</sub> = 0 V, f = 1 MHz	_	0.12	0.15	pF
Dynamic resistance	R <sub>DYN</sub>	(Note 2)	—	_	1.05	_	Ω
Electrostatic discharge voltage (IEC61000-4-2) (Contact)	V <sub>ESD</sub>	(Note 3)	—	8	_		kV

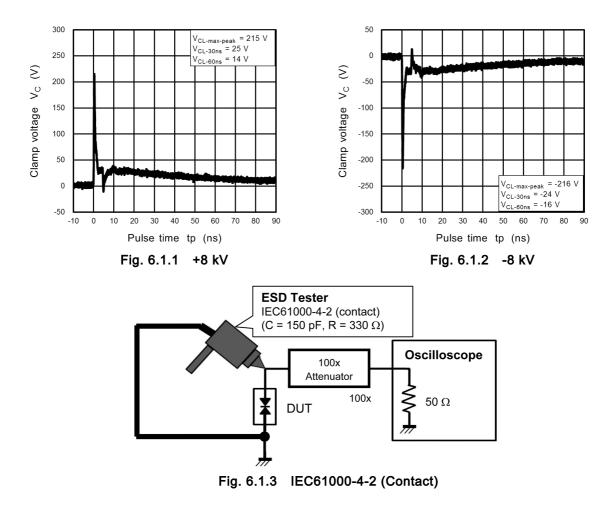
Note 1: Recommended operating condition.

Note 2: TLP parameters: Z0 = 50  $\Omega$ , tp = 100 ns, tr = 300 ps, averaging window: t1 = 30 ns to t2 = 60 ns, extraction of dynamic resistance using least squares fit of TLP characteristics between I<sub>PP1</sub> = 8 A and I<sub>PP2</sub> = 16 A.

Note 3: Criterion: No damage to devices.

### 6.1. ESD Clamp Waveform (Note)

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Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

#### 6.2. Harmonic distortion characteristics (Note)

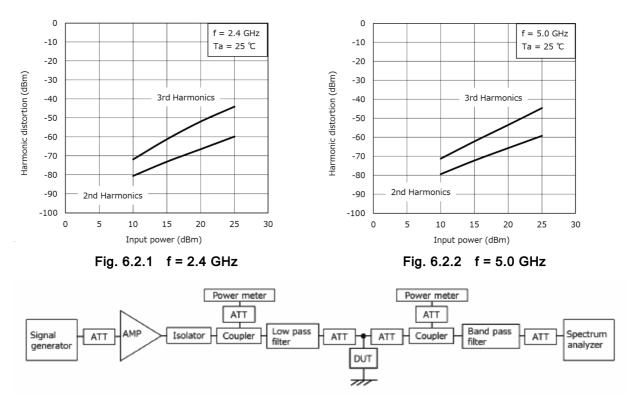
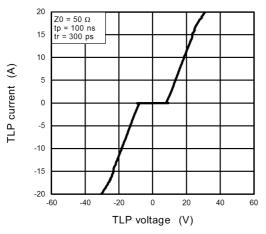


Fig. 6.2.3 Schematic diagram of harmonic distortion evaluation system

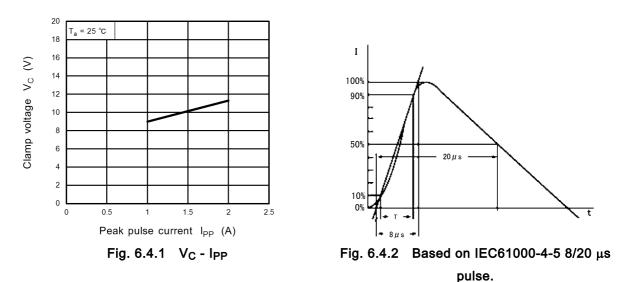
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

#### 6.3. TLP Characteristics (Note)



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

#### 6.4. Clamp Voltage - Peak Pulse Current (V<sub>C</sub> - I<sub>PP</sub>) (Note)



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

#### 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Note	Rating	Unit
Electrostatic discharge voltage (IEC61000-4-2) (Contact)	V <sub>ESD</sub>	(Note 1)	±8	kV
Electrostatic discharge voltage (IEC61000-4-2) (Air)			±8	
Peak pulse power (tp = 8/20 μs)	P <sub>PK</sub>		30	W
Peak pulse current (tp = 8/20 μs)	I <sub>PP</sub>	(Note 2)	2.0	А
Junction temperature	Тj		150	°C
Storage temperature	T <sub>stg</sub>		-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: According to IEC61000-4-2.

Note 2: According to IEC61000-4-5.

#### 8. Electrical Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

- V<sub>RWM</sub>: Working peak reverse voltage V<sub>T</sub>: Trigger voltage V<sub>H</sub>: Holding voltage (Reverse breakdown voltage) I<sub>t1</sub>: Test current (Reverse breakdown current) I<sub>R</sub>: Reverse current V<sub>C</sub>: Clamp voltage I<sub>PP</sub>: Peak pulse current
- R<sub>DYN</sub>: Dynamic resistance

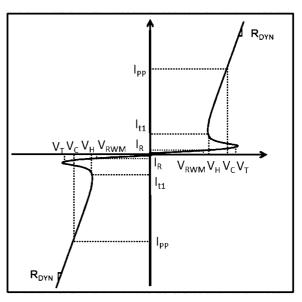


Fig. 8.1 Definitions of Electrical Characteristics

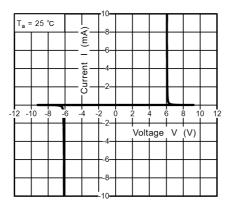
Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Working peak reverse voltage	V <sub>RWM</sub>	(Note 1)	(Note 1) —		_	5.5	V
Total capacitance	Ct		V <sub>R</sub> = 0 V, f = 1 MHz	_	0.12	0.15	pF
Dynamic resistance	R <sub>DYN</sub>	(Note 2)	—	_	1.05	_	Ω
Trigger voltage	V <sub>T</sub>		_	5.6	—	_	V
Holding voltage	V <sub>H</sub>		l <sub>t1</sub> = 1mA	5.6	6.2	8.0	V
Reverse current	I <sub>R</sub>		V <sub>RWM</sub> = 5.5 V			0.1	μA
Clamp voltage	V <sub>C</sub>	(Note 3)	I <sub>PP</sub> = 1 A	_	9	_	V
			I <sub>PP</sub> = 2 A	_	11.3	15	
		(Note 2)	I <sub>TLP</sub> = 8 A		16.5	_	V
			I <sub>TLP</sub> = 16 A		25		

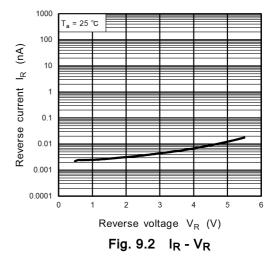
Note 1: Recommended operating condition.

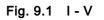
Note 2: TLP parameters: Z0 = 50  $\Omega$ , tp = 100 ns, tr = 300 ps, averaging window: t1 = 30 ns to t2 = 60 ns, extraction of dynamic resistance using least squares fit of TLP characteristics between I<sub>PP1</sub> = 8 A and I<sub>PP2</sub> = 16 A.

Note 3: Based on IEC61000-4-5 8/20 µs pulse.

#### 9. Characteristics Curves (Note)







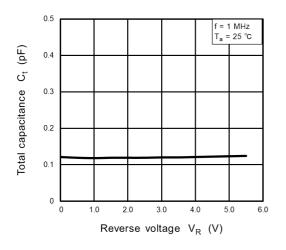
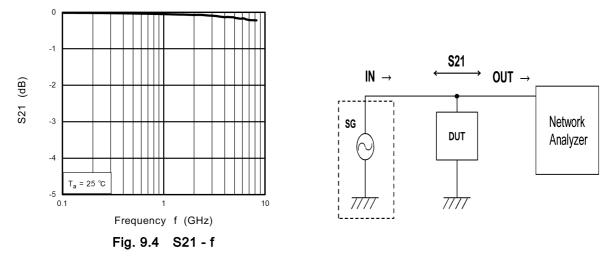
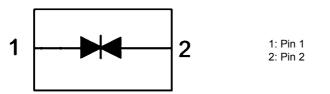


Fig. 9.3  $C_t - V_R$ 



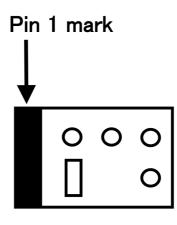
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

#### 10. Internal Circuit (Note)

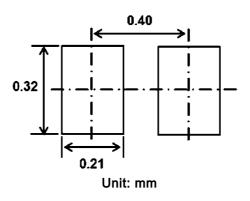


Note: Connect Pin 2 to GND when using Pin 1 for I/O. Connect Pin 1 to GND when using Pin 2 for I/O.

#### 11. Marking (Top view)



12. Land Pattern Dimensions (for reference only)

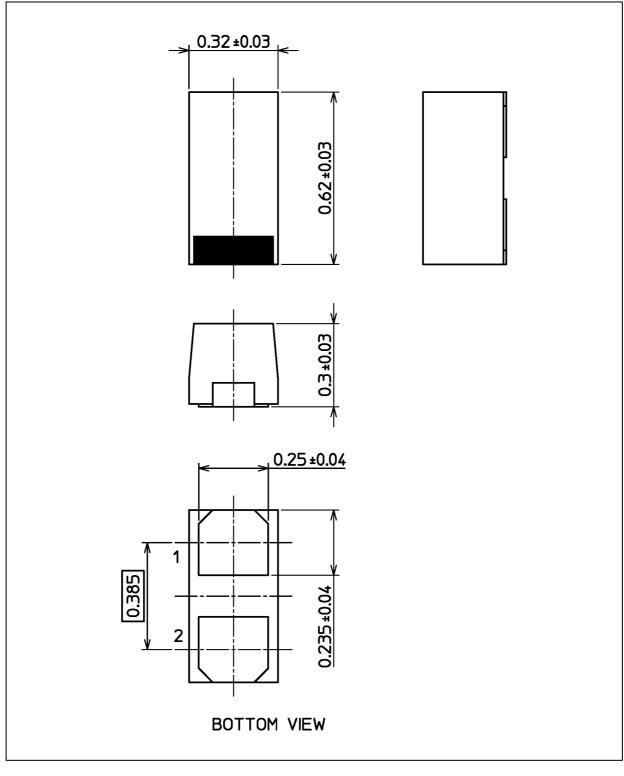




### DF2B6M4BSL

#### **Package Dimensions**

Unit: mm



Weight: 0.2 mg (typ.)

Package Name(s)

Nickname: SL2

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